

FQD12N20LTM_F085

FQD12N20LTM_F085 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



FQD12N20LTM_F085 Specifications

Manufacturer Fairchild/ON Semiconductor Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single Package TO-252-3, DPak (2 Leads + Tab), SC-63 Series Automotive, AEC-Q101, QFET? FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 200V Current - Continuous Drain (Id) @ 25°C 9A (Tc) Drive Voltage (Max Rds On, Min Rds On) 5V, 10V Vgs(th) (Max) @ Id 2V @ 250µA Gate Charge (Qg) (Max) @ Vgs 1080pF @ 25V Vgs (Max) ±20V FET Feature - Power Dissipation (Max) 2.5W (Ta), 55W (Tc) Rds On (Max) @ Id, Vgs 280 mOhm @ 4.5A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package D-Pak Package / Case TO-252-3, DPak (2 Leads + Tab), SC-63		
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TechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)200VCurrent - Continuous Drain (Id) @ 25°C9A (Tc)Drive Voltage (Max Rds On, Min Rds On)5V, 10VVgs(th) (Max) @ Id2V @ 250µAGate Charge (Qg) (Max) @ Vgs21nC @ 5VInput Capacitance (Ciss) (Max) @ Vds1080pF @ 25VVgs (Max)±20VFET Feature-Power Dissipation (Max)2.5W (Ta), 55W (Tc)Rds On (Max) @ Id, Vgs280 mOhm @ 4.5A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Series	Automotive, AEC-Q101, QFET?
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Drive Voltage (Max Rds On, Min Rds On) 5V, 10V Vgs(th) (Max) @ Id 2V @ 250μA Gate Charge (Qg) (Max) @ Vgs 21nC @ 5V Input Capacitance (Ciss) (Max) @ Vds 1080pF @ 25V Vgs (Max) ±20V FET Feature - Power Dissipation (Max) 2.5W (Ta), 55W (Tc) Rds On (Max) @ Id, Vgs 280 mOhm @ 4.5A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package D-Pak Package / Case TO-252-3, DPak (2 Leads + Tab), SC-63	Drain to Source Voltage (Vdss)	200V
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Gate Charge (Qg) (Max) @ Vgs21nC @ 5VInput Capacitance (Ciss) (Max) @ Vds1080pF @ 25VVgs (Max)±20VFET Feature-Power Dissipation (Max)2.5W (Ta), 55W (Tc)Rds On (Max) @ Id, Vgs280 mOhm @ 4.5A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Drive Voltage (Max Rds On, Min Rds On)	5V, 10V
Input Capacitance (Ciss) (Max) @ Vds1080pF @ 25VVgs (Max)±20VFET Feature-Power Dissipation (Max)2.5W (Ta), 55W (Tc)Rds On (Max) @ Id, Vgs280 mOhm @ 4.5A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Vgs(th) (Max) @ Id	2V @ 250µA
Ygs (Max)±20VFET Feature-Power Dissipation (Max)2.5W (Ta), 55W (Tc)Rds On (Max) @ Id, Vgs280 mOhm @ 4.5A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Gate Charge (Qg) (Max) @ Vgs	21nC @ 5V
FET Feature-Power Dissipation (Max)2.5W (Ta), 55W (Tc)Rds On (Max) @ Id, Vgs280 mOhm @ 4.5A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Input Capacitance (Ciss) (Max) @ Vds	1080pF @ 25V
Power Dissipation (Max)2.5W (Ta), 55W (Tc)Rds On (Max) @ Id, Vgs280 mOhm @ 4.5A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Vgs (Max)	±20V
Rds On (Max) @ Id, Vgs280 mOhm @ 4.5A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	FET Feature	-
Operating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Power Dissipation (Max)	2.5W (Ta), 55W (Tc)
Mounting TypeSurface MountSupplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Rds On (Max) @ Id, Vgs	280 mOhm @ 4.5A, 10V
Supplier Device PackageD-PakPackage / CaseTO-252-3, DPak (2 Leads + Tab), SC-63	Operating Temperature	-55°C ~ 150°C (TJ)
Package / Case TO-252-3, DPak (2 Leads + Tab), SC-63	Mounting Type	Surface Mount
	Supplier Device Package	D-Pak
Report errors?	Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
		Report errors?

FQD12N20LTM_F085 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

FQD12N20LTM_F085 Payment Methods



If you have any question about FQD12N20LTM_F085, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com